NSN 5961-01-501-9126

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-501-9126 **Inclosure Material:** Metal **Overall Length:** Between 0.106 inches and 0.160 inches **Overall Diameter:** Between 0.060 inches and 0.085 inches **End Application:** Nuclear power plants **Mounting Facility Quantity: Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.42 regulator voltage, dc and 3.78 regulator voltage, dc and 1.00 reverse voltage, instantaneous **Current Rating Per Characteristic:** 50.00 microamperes collector current, dc peak **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No